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[ON Semiconductor](#)  
[MMFT107T1](#)

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# MMFT107T1

Preferred Device

## Power MOSFET 250 mA, 200 Volts N-Channel SOT-223

This Power MOSFET is designed for high speed, low loss power switching applications such as switching regulators, dc-dc converters, solenoid and relay drivers. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

- Silicon Gate for Fast Switching Speeds
- Low Drive Requirement
- The SOT-223 Package can be soldered using wave or reflow. The formed leads absorb thermal stress during soldering eliminating the possibility of damage to the die.

### MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	200	Volts
Gate-to-Source Voltage – Non-Repetitive	V <sub>GS</sub>	±20	Volts
Drain Current	I <sub>D</sub>	250	mA <sub>dc</sub>
Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 1.) Derate above 25°C	P <sub>D</sub>	0.8	Watts
		6.4	mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to 150	°C

### THERMAL CHARACTERISTICS

Thermal Resistance – Junction-to-Ambient	R <sub>θJA</sub>	156	°C/W
Maximum Temperature for Soldering Purposes Time in Solder Bath	T <sub>L</sub>	260	°C
		10	Sec

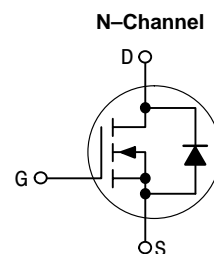
1. Device mounted on FR-4 glass epoxy printed circuit using minimum recommended footprint.



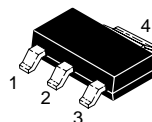
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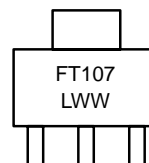
**250 mA**  
**200 VOLTS**  
**R<sub>DS(on)</sub> = 14 Ω**



### MARKING DIAGRAM

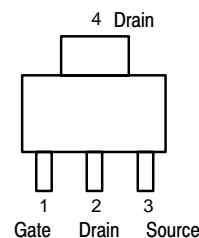


TO-261AA  
 CASE 318E  
 STYLE 3



L = Location Code  
 WW = Work Week

### PIN ASSIGNMENT



### ORDERING INFORMATION

Device	Package	Shipping
MMFT107T1	SOT-223	1000 Tape & Reel
MMFT107T3	SOT-223	4000 Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

## MMFT107T1

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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#### OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 10 μA)	V <sub>(BR)DSS</sub>	200	-	-	Vdc
Zero Gate Voltage Drain Current (V <sub>DS</sub> = 130 V, V <sub>GS</sub> = 0)	I <sub>DSS</sub>	-	-	30	nAdc
Gate-Body Leakage Current – Reverse (V <sub>GS</sub> = 15 Vdc, V <sub>DS</sub> = 0)	I <sub>GSS</sub>	-	-	10	nAdc

#### ON CHARACTERISTICS (Note 2.)

Gate Threshold Voltage (V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mAdc)	V <sub>GS(th)</sub>	1.0	-	3.0	Vdc
Static Drain-to-Source On-Resistance (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 200 mA)	R <sub>DS(on)</sub>	-	-	14	Ohms
Drain-to-Source On-Voltage (V <sub>GS</sub> = 10 V, I <sub>D</sub> = 200 mA)	V <sub>DS(on)</sub>	-	-	2.8	Vdc
Forward Transconductance (V <sub>DS</sub> = 25 V, I <sub>D</sub> = 250 mA)	g <sub>fs</sub>	-	300	-	mmhos

#### DYNAMIC CHARACTERISTICS

Input Capacitance	(V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	-	60	-	pF
Output Capacitance		C <sub>oss</sub>	-	30	-	
Transfer Capacitance		C <sub>rss</sub>	-	6.0	-	

#### SOURCE DRAIN DIODE CHARACTERISTICS

Diode Forward Voltage	(V <sub>GS</sub> = 0, I <sub>S</sub> = 250 mA)	V <sub>F</sub>	-	0.8	-	V
Continuous Source Current, Body Diode		I <sub>S</sub>	-	-	250	mA
Pulsed Source Current, Body Diode		I <sub>SM</sub>	-	-	500	

2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

### TYPICAL ELECTRICAL CHARACTERISTICS

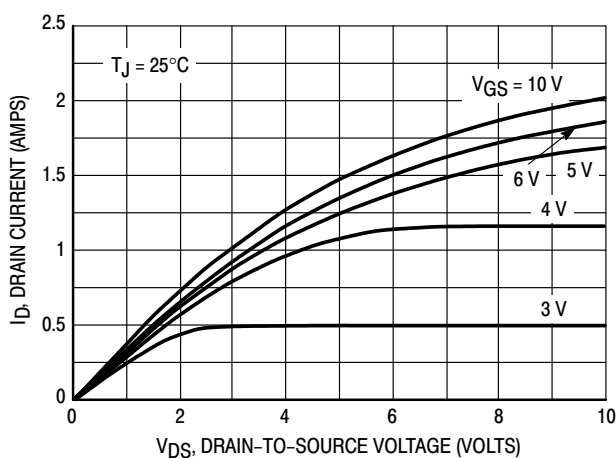


Figure 1. On-Region Characteristics

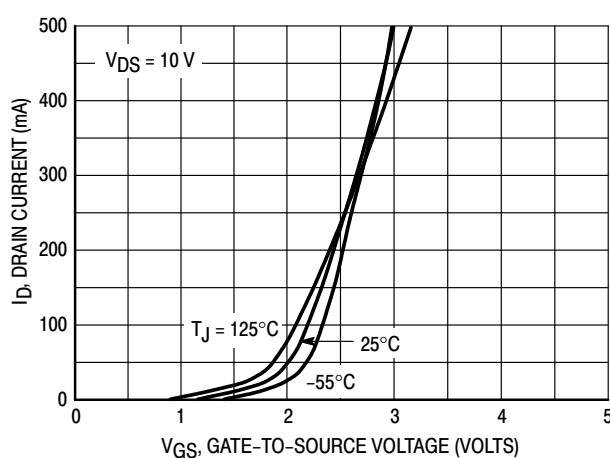
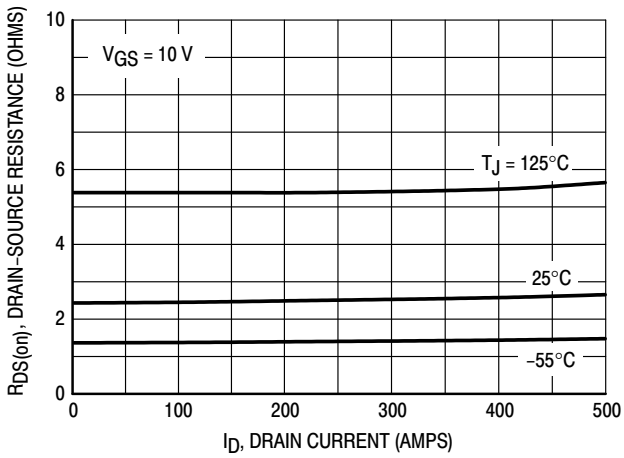


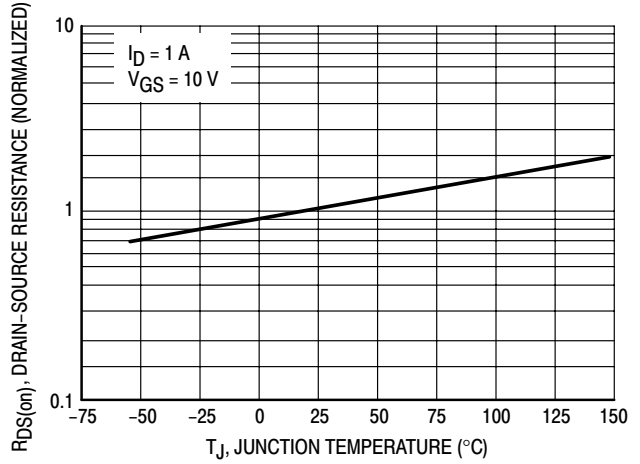
Figure 2. Transfer Characteristics

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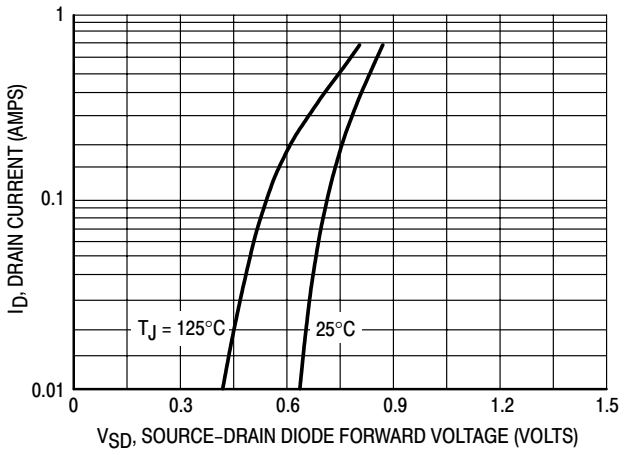
**TYPICAL ELECTRICAL CHARACTERISTICS**



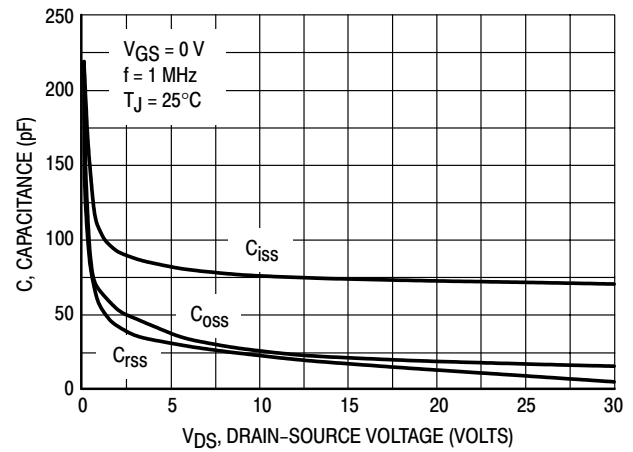
**Figure 3. On-Resistance versus Drain Current**



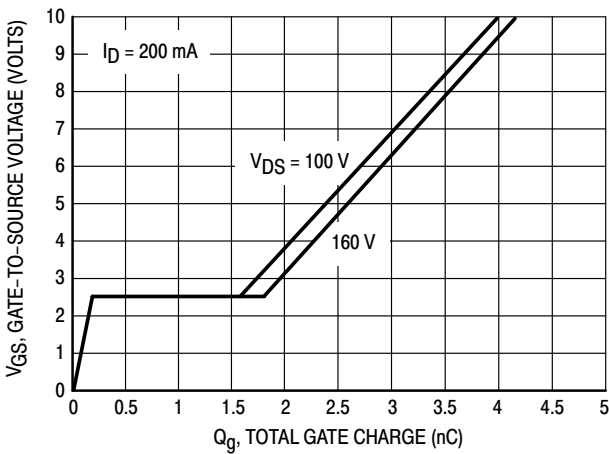
**Figure 4. On-Resistance Variation with Temperature**



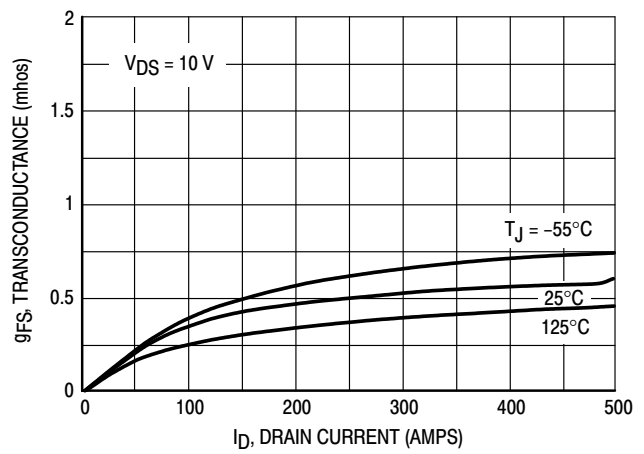
**Figure 5. Source-Drain Diode Forward Voltage**



**Figure 6. Capacitance Variation**



**Figure 7. Gate Charge versus Gate-to-Source Voltage**



**Figure 8. Transconductance**

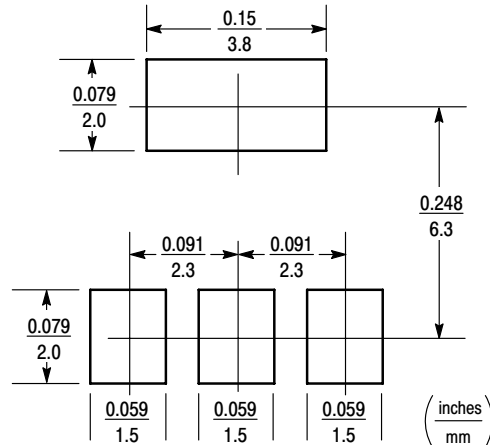
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### INFORMATION FOR USING THE SOT-223 SURFACE MOUNT PACKAGE

#### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



#### SOT-223 POWER DISSIPATION

The power dissipation of the SOT-223 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-223 package,  $P_D$  can be calculated as follows:

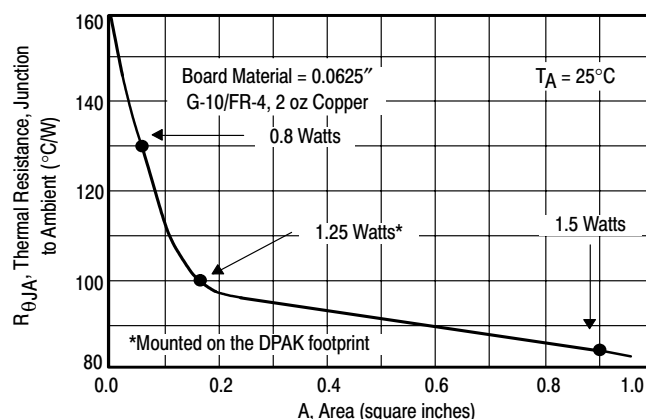
$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 0.8 watts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{156^\circ\text{C/W}} = 0.8 \text{ watts}$$

The 156°C/W for the SOT-223 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 0.8 watts. There are other alternatives to achieving higher power dissipation from the SOT-223 package. One is to increase the area of the collector pad. By increasing the area of the collector pad, the power dissipation can be increased. Although the power dissipation can almost be doubled with this method, area is taken up on the printed circuit board which can defeat the purpose of using surface mount technology. A graph of  $R_{\theta JA}$  versus collector pad area is shown in Figure 9.

## MMFT107T1



**Figure 9. Thermal Resistance versus Collector Pad Area for the SOT-223 Package (Typical)**

Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core

board, the power dissipation can be doubled using the same footprint.

### SOLDER STENCIL GUIDELINES

Prior to placing surface mount components onto a printed circuit board, solder paste must be applied to the pads. A solder stencil is required to screen the optimum amount of solder paste onto the footprint. The stencil is made of brass

or stainless steel with a typical thickness of 0.008 inches. The stencil opening size for the SOT-223 package should be the same as the pad size on the printed circuit board, i.e., a 1:1 registration.

### SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference should be a maximum of 10°C.

- The soldering temperature and time should not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient should be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling

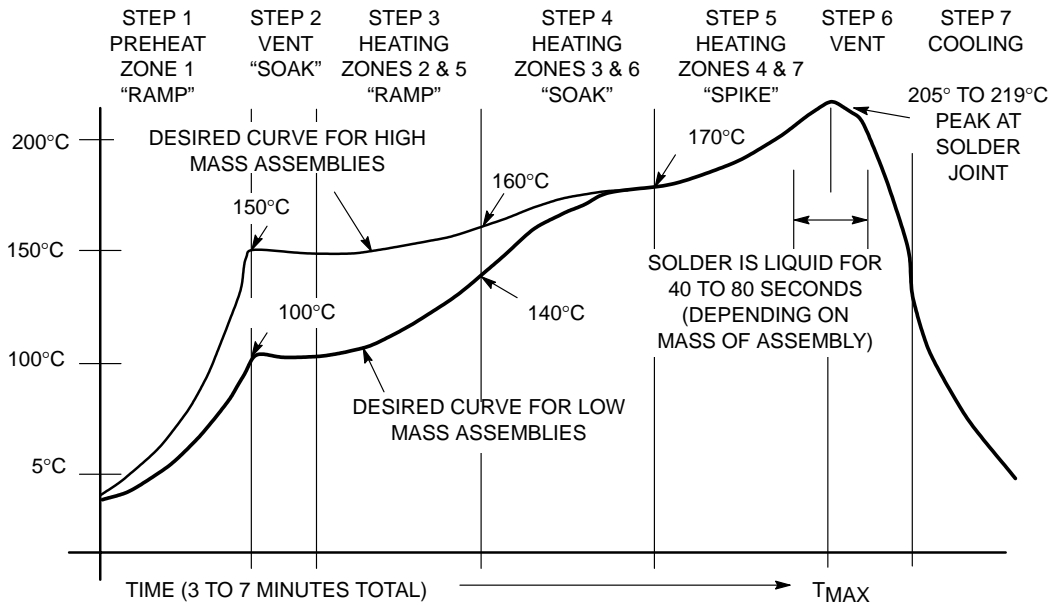
\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

**MMFT107T1**

**TYPICAL SOLDER HEATING PROFILE**

For any given circuit board, there will be a group of control settings that will give the desired heat pattern. The operator must set temperatures for several heating zones, and a figure for belt speed. Taken together, these control settings make up a heating “profile” for that particular circuit board. On machines controlled by a computer, the computer remembers these profiles from one operating session to the next. Figure 10 shows a typical heating profile for use when soldering a surface mount device to a printed circuit board. This profile will vary among soldering systems but it is a good starting point. Factors that can affect the profile include the type of soldering system in use, density and types of components on the board, type of solder used, and the type of board or substrate material being used. This profile shows temperature versus time.

The line on the graph shows the actual temperature that might be experienced on the surface of a test board at or near a central solder joint. The two profiles are based on a high density and a low density board. The Vitronics SMD310 convection/infrared reflow soldering system was used to generate this profile. The type of solder used was 62/36/2 Tin Lead Silver with a melting point between 177–189°C. When this type of furnace is used for solder reflow work, the circuit boards and solder joints tend to heat first. The components on the board are then heated by conduction. The circuit board, because it has a large surface area, absorbs the thermal energy more efficiently, then distributes this energy to the components. Because of this effect, the main body of a component may be up to 30 degrees cooler than the adjacent solder joints.



**Figure 10. Typical Solder Heating Profile**

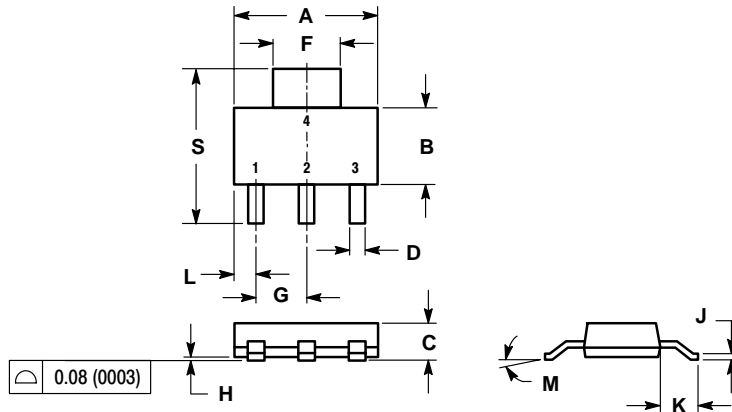
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**PACKAGE DIMENSIONS**

**SOT-223 (TO-261)**

CASE 318E-04

ISSUE K



- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.249	0.263	6.30	6.70
B	0.130	0.145	3.30	3.70
C	0.060	0.068	1.50	1.75
D	0.024	0.035	0.60	0.89
F	0.115	0.126	2.90	3.20
G	0.087	0.094	2.20	2.40
H	0.0008	0.0040	0.020	0.100
J	0.009	0.014	0.24	0.35
K	0.060	0.078	1.50	2.00
L	0.033	0.041	0.85	1.05
M	0°	10°	0°	10°
S	0.264	0.287	6.70	7.30

- STYLE 3:  
 PIN 1. GATE  
 2. DRAIN  
 3. SOURCE  
 4. DRAIN



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